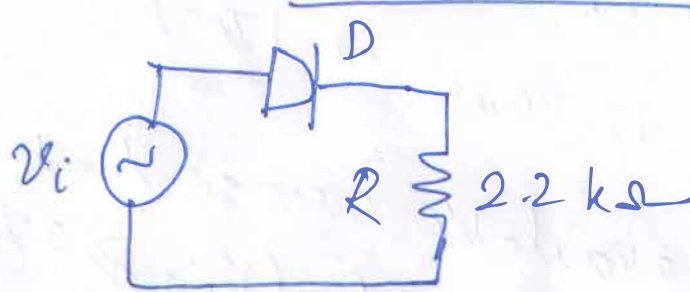


1.



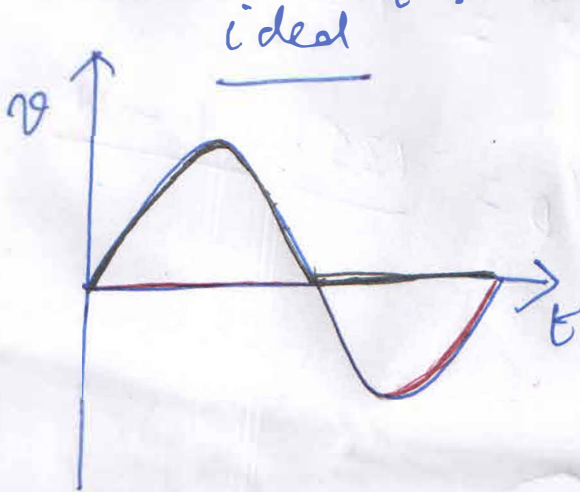
$$v_i = 10 \sin(\omega t)$$

$$f = 60 \text{ Hz} = \omega$$

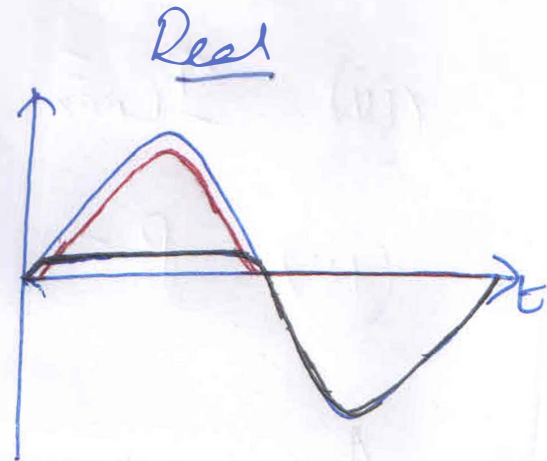
Ideal diode: no voltage drop in forward bias. So voltage drops across R entire voltage drops across D in reverse bias.

Real diode, V_D is fixed at 0.7V (for Si)

when $v_i \geq 0.7$ then $v_D = v_i$



—: input (v_i)
 —: V_R
 —: v_D



—: v_i
 —: across diode
 —: across R

2. Irrespective of v_i , $V_R = 2V$
 (R is in parallel with 2V source)

(2)

3 $V_{RMS} = 120V$

$$V_{peak} = \sqrt{2} V_{RMS} \sim 170V$$

(i) Voltage available across load
 $V_{in} - 2V_D$ for $(V_{in} \geq 2V_D)$
 else 0

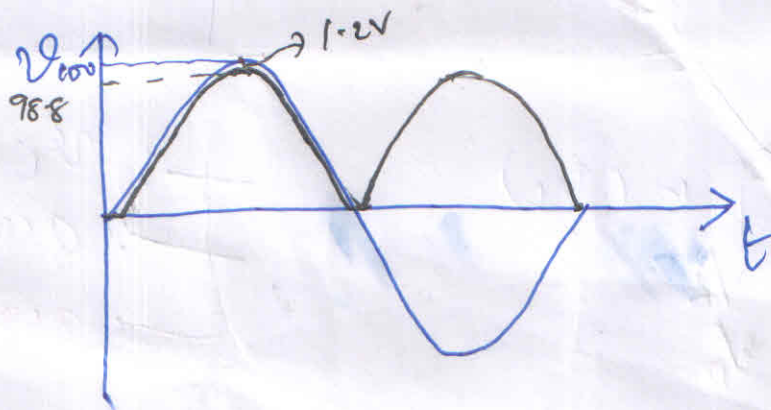
$$V_{Lmax} = 170 - 2 \times 0.6 = 168.8V$$

(ii) Each reverse biased diode should hold
 a maximum of $\frac{V_{Lmax}}{2} = \underline{84.4V}$ in
 reverse bias

(iii) $I_{Lmax} = \frac{V_{Lmax}}{R} = 168.8mA$ ($R = 1k\Omega$)

(iv) $P = I_{Lmax} \cdot V_D = \underline{135.04mW}$

4.



—: v_{in}
 —: v_R

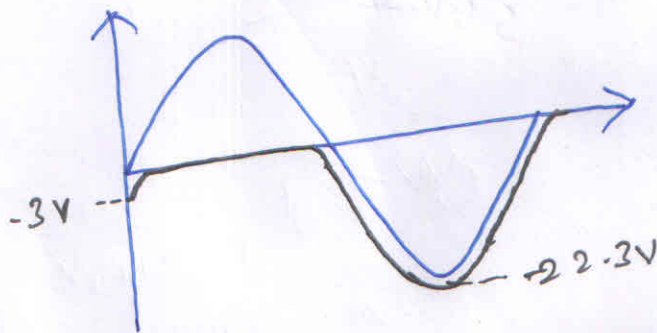
5 a) for $v_i \leq 3V$ battery ensures diode is 3
 for ward bias. Hence voltage across diode is
 0.7 V. $v_o = (v_i - 3)V$ (v_o is across R)

for at $v_i = 3V$, $v_o = 0V$

at $v_i = -20V$, $v_o = -20 - 3 = -23V$

(considering real diode) an

$$v_o = v_i - 3 + V_D = -22.3V$$



—: Input
 —: Output

b) for positive pulse of v_i :

$$v_o = 10 - 0.7 + 5 = \underline{14.3V}$$

for negative pulse of v_i as diode is off,

$$v_o = \underline{0V}$$

6 During positive pulse of v_i :

diode is "on" and $v_o = -2 + 0.6V = -1.4V$

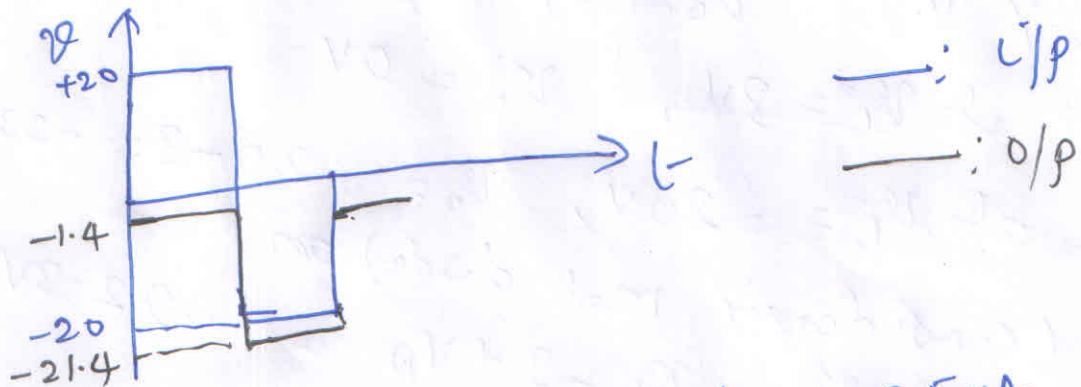
Capacitor charges to $10 + 2 - 0.6 = 11.4V$

($\tau = RC = 5.6ms$. $5\tau = 28ms \gg \frac{1}{f}$ (1100s))

(4)

In the negative pulse of v_i ,

diode is off and $v_o = -10 - 11.4 = -21.4$



$$I_R = \frac{v_o}{R} = \frac{-1.4 \text{ V}}{56 \text{ k}\Omega} = \underline{25 \mu\text{A}}$$